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# 2SC2290A

TOSHIBA TRANSISTOR SILICON NPN EPITAXIAL PLANAR TYPE



# 2~30MHz SSB LINEAR POWER AMPLIFIER APPLICATIONS (LOW SUPPLY VOLTAGE USE)

- Specified 12.5V, 28MHz Characteristics
- Output Power : Po = 60WPEP (Min.)
- Power Gain : Gp = 11.8dB (Min.)
- Collector Efficiency :  $\eta_{\rm C} = 35\%$  (Min.)
- Intermodulation Distortion: IMD = -30dB (Max.)

### MAXIMUM RATINGS (Tc = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V <sub>CBO</sub>	45	V
Collector-Emitter Voltage	V <sub>CES</sub>	45	V
Collector-Emitter Voltage	V <sub>CEO</sub>	18	V
Emitter-Base Voltage	VEBO	4	V
Collector Current	IC	20	А
Collector Power Dissipation	PC	175	W
Junction Temperature	Tj	175	°C
Storage Temperature Range	T <sub>stg</sub>	-65~175	°C



### MARKING





# ELECTRICAL CHARACTERISTICS (Tc = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector-Emitter Breakdown Voltage	V (BR) CEO	I <sub>C</sub> = 100mA, I <sub>B</sub> = 0	18	_	_	V
Collector-Emitter Breakdown Voltage	V (BR) CES	I <sub>C</sub> = 100mA, V <sub>EB</sub> = 0	45		_	V
Emitter-Base Breakdown Voltage	V (BR) EBO	I <sub>E</sub> = 1mA, I <sub>C</sub> = 0	4	_	_	V
DC Current Gain	h <sub>FE</sub>	V <sub>CE</sub> = 5V, I <sub>C</sub> = 10A *	10	_	150	_
Collector Output Capacitance	C <sub>ob</sub>	V <sub>CB</sub> = 12.5V, I <sub>E</sub> = 0 f = 1MHz	_	_	500	pF
Power Gain	Gp		11.8	13.8	_	dB
Input Power	Pi	V <sub>CC</sub> = 12.5V, f <sub>1</sub> = 28.000MHz, f <sub>2</sub> = 28.001MHz	_	2.5	4	WPEP
Collector Efficiency	ηc	$I_{idle} = 50 \text{mA}$ Po = 60Wppp (Fig.)	35	_	_	%
Intermodulation Distortion	IMD		_	_	-30	dB
Series Equivalent Input Impedance	Z <sub>in</sub>	$V_{CC} = 12.5V, f_1 = 28.000MHz,$	_	1.02 −j0.17	_	Ω
Series Equivalent Output Impedance	Z <sub>out</sub>	Po = 60W <sub>PEP</sub>	_	0.86 -j0.21	_	Ω

\* Pulse Test: Pulse Width  $\leq$  100µs, Duty Cycle  $\leq$  3%

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Handbook" etc..

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### Fig. Pi TEST CIRCUIT



## CAUTION

These are only typical curves and devices are not necessarily guaranteed at these curves.